

Introduction

The electrical appliances we use in our daily lives — from lights to computers — typically go through a shutdown process when they turn off. Power supplies require stable shutdown processes that can control for unexpected overshoot. In a stable shutdown process, the power supply smoothly drops the input voltage (V_{IN}) to 0V.

For a stable shutdown, there should be a steady V_{IN} drop, no negative output voltage (V_{OUT}) overshoot, and no V_{IN} or V_{OUT} rebound. This article will discuss three unstable waveforms that can be observed during the power supply shutdown process. For the sake of this article, they will be designated as one of three classes: Class R (with a quick V_{IN} and V_{OUT} rebound), Class G (negative V_{OUT} overshoot), and Class B (with a delayed V_{IN} and V_{OUT} rebound).

Class R Shutdown (Quick V_{IN} and V_{OUT} Rebound)

Figure 1 shows the Class R shutdown waveform. In a Class R shutdown, V_{IN} steadily drops as the device shuts down, briefly increases during an energy spike, then begins to steadily drop again.

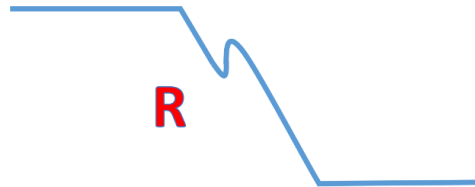


Figure 1: Class R Shutdown Waveform

There are two types of Class R waveforms, which are described below.

Class R Shutdown (Type I)

A Class R Type I shutdown occurs when the DC/DC [converter](#) restarts.

Consider a standard shutdown. If V_{IN} drops to the chip's turn-off threshold, the chip shuts down. V_{OUT} drops during this process, causing the current to suddenly decrease. However, if the chip's input line has nowhere to release the excess energy from the inductive reactance during this process, then V_{IN} sharply increases.

If V_{IN} exceeds the chip's operating threshold, the chip resumes operation and results in a non-monotonous shutdown waveform. A Class R waveform is classified as Type I if there is a switch present on the SW side (see Figure 2).

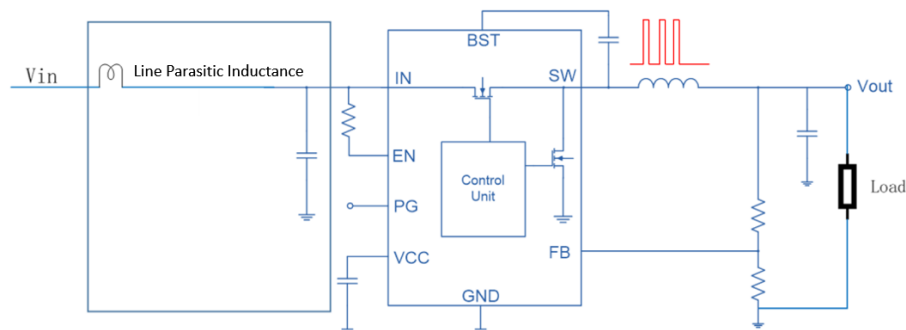


Figure 2: Line Parasitic Inductance of Class R Type I Shutdown

The Class R Type I waveform is relatively simple to prevent. The chip's specifications provide the enable (EN) and V_{IN} under-voltage lockout (UVLO) parameters. Figure 3 shows the enable and UVLO specifications for the [MPM3683-7](#), a [step-down power module](#).

Enable and Under-Voltage Lockout (UVLO)						
Enable input rising threshold	V_{IHEN}		1.17	1.22	1.27	V
Enable hysteresis	V_{EN-HYS}			200		mV
Enable input current	I_{EN}	$V_{EN} = 2V$		0		μA
Soft shutdown discharge MOSFET	R_{ON_DISCH}			80	150	Ω
VIN UVLO						
VIN under-voltage lockout threshold rising	V_{INVth_Rise}	$V_{CC} = 3.3V$	2.1	2.4	2.7	V
VIN under-voltage lockout threshold falling	V_{INVth_Fall}		1.55	1.85	2.15	V

Figure 3: MPM3683-7 Specifications

With these specifications in mind, there are two methods to avoid an unstable shutdown, described below:

1. Reduce the V_{IN} bounce by optimizing input filtering, reducing input inductance, selecting a capacitor with a larger capacitance and smaller equivalent series resistance (ESR) and equivalent series inductance (ESL), and placing the input capacitor as close to the IC as possible.
2. Select appropriate upper and lower voltage resistor dividers for EN, such that EN turns off when V_{IN} drops to its UVLO threshold. This can prevent the IC from starting up again.

Class R Shutdown (Type II)

If the load is suddenly reduced, the excess energy stored in the integrated output inductor or the output line inductor cannot be released anywhere (see Figure 4). This can significantly increase V_{OUT} for a short time.

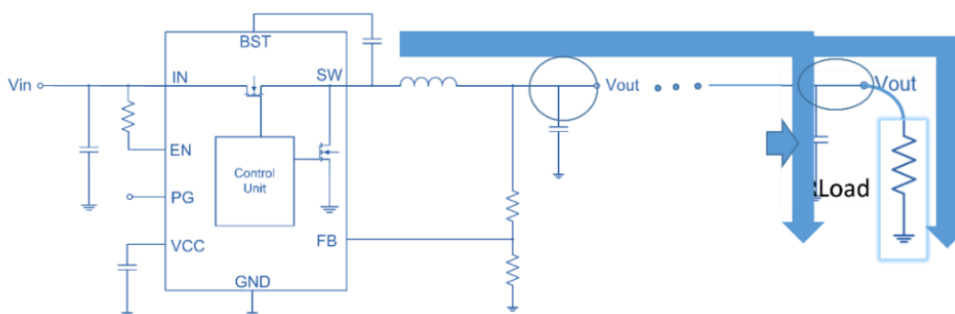


Figure 4: Class R Type II Event

To prevent a Class R Type II event, it is critical to optimize the output line. To optimize this line and reduce the chances of a rebound, reduce the line's inductive reactance and increase the capacitance at the load terminal.

Class G Waveform (Negative Overshoot)

Figure 5 shows the Class G shutdown waveform. In a Class G shutdown, V_{OUT} drops steadily, then drops rapidly past its target (called negative overshoot) before rising back to its target value.



Figure 5: Class G Shutdown Waveform

Similar to Class R waveforms, Class G waveforms can be subdivided into two types.

Class G Shutdown (Type I)

If the buck circuit's low-side MOSFET (LS-FET) does not turn off during shutdown, the inductor current continues to reverse. This situation is more common under no-load and light-loads conditions, and it can result in V_{OUT} dropping too low.

To prevent this issue, the DC/DC [converter](#) typically adds zero-current detection (ZCD) during shutdown, then automatically turns off the LS-FET when it detects that the current has reached 0A (commonly called the ZCD point) (see Figure 6). This approach can effectively prevent negative overshoot during shutdown.

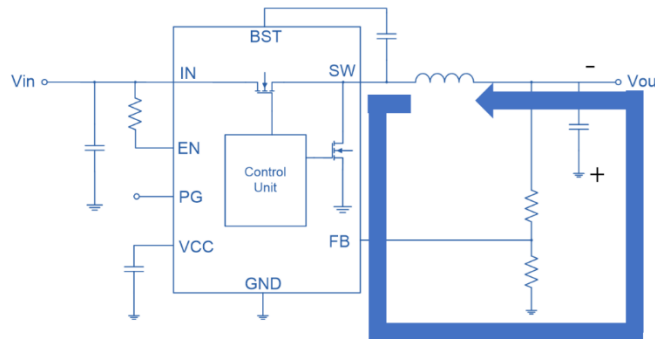


Figure 6: Preventing Negative Overshoot in Class G Type I

Class G Shutdown (Type II)

V_{OUT} can experience negative overshoot due to the parasitic inductive reactance on the output line (see Figure 7). This type of shutdown is more likely to occur under heavy loads or during output short-circuit faults.

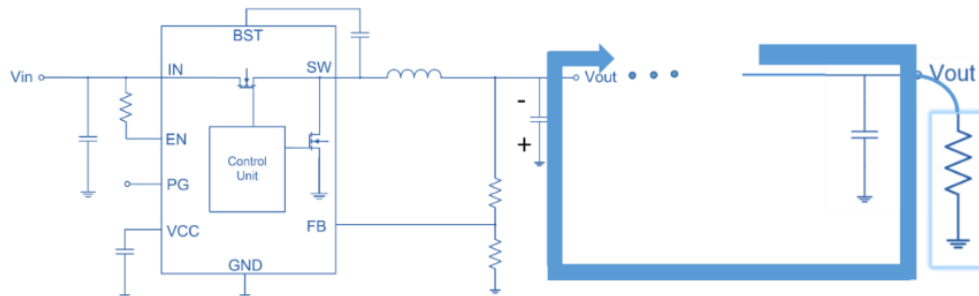


Figure 7: Reduce Parasitic Inductive Reactance of Class G Type II

The output line's inductive reactance must be minimized to prevent Class G Type II shutdown. In addition, the load terminal's capacitance should be increased.

Class B Waveform (Delayed V_{IN} and V_{OUT} Rebound)

Figure 8 shows a Class B shutdown waveform, which occurs under heavy loads. In a Class B waveform, both V_{IN} and V_{OUT} fall sharply, rise for a short period of time, then remain stable (as with V_{OUT}) or fall again (as with V_{IN}). Both scenarios are referred to as a rebound.

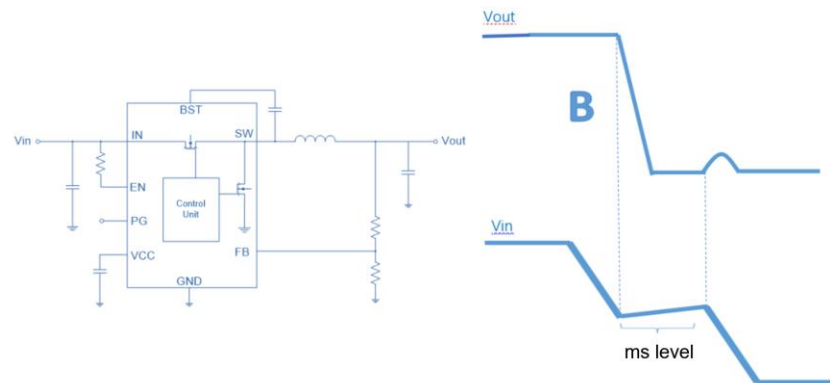


Figure 8: Class B Shutdown Waveform under Heavy Loads

Class B waveforms look similar to Class R waveforms, but Class R waveforms are due to the line inductance, and Class B waveforms have a much later rebound. After the first shutdown, V_{OUT} and V_{IN} typically rebound in microseconds with Class R shutdowns; however, V_{OUT} and V_{IN} may not rebound for up to tens of milliseconds in Class B shutdowns.

The dielectric absorption effect leads to the Class B waveform. If the input capacitor's discharge current is large then suddenly drops to 0A, the dielectric in the capacitor slowly releases some of the previously absorbed charges. Once the discharge current reaches the chip's start-up voltage again, V_{OUT} rebounds.

To prevent a Class B shutdown, a chip can be powered off through EN, similar to the method used for Class R Type I shutdowns. Select the V_{IN} under-voltage protection (UVP) threshold and hysteresis to ensure that EN stays off. Then the V_{IN} rebound does not exceed the chip's power-on threshold and lead to an accidental restart. In addition, static loads can be added to consume any excess charge.

Conclusion

This article explored three different types of shutdown waveforms (Class R, Class G, and Class B) related to the power supply shutdown process, with the intent of improving stability and preventing negative overshoot. These classes were also further subdivided, depending on the excess energy and loads conditions.

For more details, explore MPS's robust selection of [step-down power modules](#).